

YJ Planar Schottky Barrier Diode Die Specification

100V 1A, 28mil, Schottky barrier diode die based on silicon planar process

Part No.: PSB028S100SS-280A

Main Products Characteristics

- Average forward current: $I_F(AV) = 1\text{ A}$
- Maximum operating junction temperature: $T_j = 175\text{ }^{\circ}\text{C}$